

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

### FCP36N60N

### • FEATURES

- With TO-220 packaging
- High speed switching
- · Very high commutation ruggedness
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz

• ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25℃)

#### APPLICATIONS

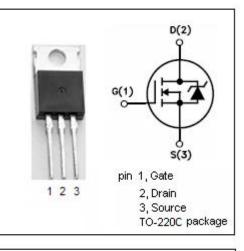
- PFC stages
- LCD & PDP TV
- Power supply
- Switching applications

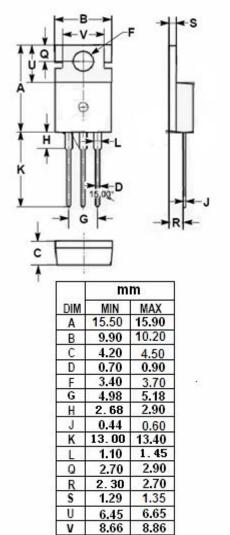
SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	600	V	
V <sub>GSS</sub>	Gate-Source Voltage	±30	V	
ID	Drain Current-Continuous@Tc=25℃ Tc=100℃	36 22.7	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	108	А	
PD	Total Dissipation	312	W	
Tj	Operating Junction Temperature	-55~150	°C	
T <sub>stg</sub>	Storage Temperature	-55~150	°C	

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.4	°C <b>/W</b>	
Rth(ch-a)	h-a) Channel-to-ambient thermal resistance		°C <b>/W</b>	

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isc website: www.iscsemi.cn





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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1mA	600			V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> =10V; I <sub>D</sub> =0.25mA	2.0		4.0	V
$R_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =18A		81	90	mΩ
Igss	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V			±0.1	μ Α
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 480V; V <sub>GS</sub> = 0V;Tj=25℃ V <sub>DS</sub> = 480V; V <sub>GS</sub> = 0V;Tj=125℃			10 100	μ Α
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =18A, V <sub>GS</sub> = 0 V			1.2	V

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